

1.2V Drive Nch MOSFET

RUE002N02

●Structure

Silicon N-channel
MOSFET

●Applications

Switching

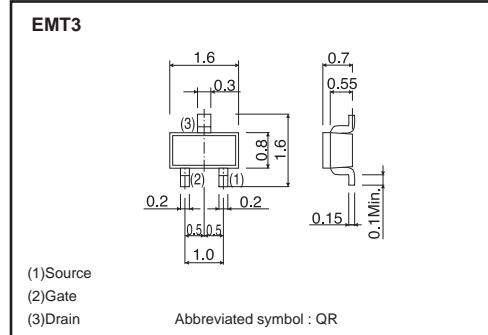
●Features

- 1) Fast switching speed.
- 2) Low voltage drive (1.2V) makes this device ideal for portable equipment.
- 3) Drive circuits can be simple.

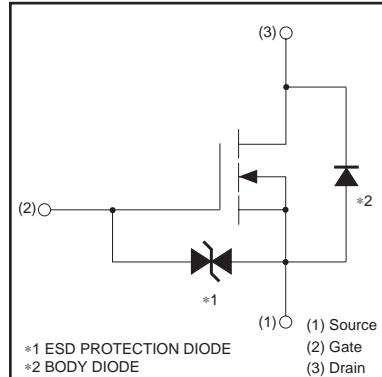
●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
	RUE002N02	○

●Dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	V _{DSS}	20	V
Gate-source voltage	V _{GSS}	±8	V
Drain current	Continuous	I _D	mA
	Pulsed	I _{DP} *1	mA
Total power dissipation	P _D *2	150	mW
Channel temperature	T _{Ch}	150	°C
Range of storage temperature	T _{Stg}	-55 to +150	°C

*1 P_W≤10μs, Duty cycle≤1%

*2 Each terminal mounted on a recommended land

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	R _{th(ch-a)} *	833	°C / W

* Each terminal mounted on a recommended land

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	—	—	±10	µA	V _{GS} =±8V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR)DSS}	20	—	—	V	I _D =1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	—	—	1	µA	V _{DS} =20V, V _{GS} =0V
Gate threshold voltage	V _{GS(th)}	0.3	—	1	V	V _{DS} =10V, I _D =1mA
Static drain-source on-state resistance	R _{D(on)} *	—	0.8	1.2	Ω	I _D =200mA, V _{GS} =2.5V
		—	1.0	1.4	Ω	I _D =200mA, V _{GS} =1.8V
		—	1.2	2.4	Ω	I _D =40mA, V _{GS} =1.5V
		—	1.6	4.8	Ω	I _D =20mA, V _{GS} =1.2V
Forward transfer admittance	Y _{fs} *	200	—	—	mS	V _{DS} =10V, I _D =200mA
Input capacitance	C _{iss}	—	25	—	pF	V _{DS} =10V V _{GS} =0V
Output capacitance	C _{oss}	—	10	—	pF	f=1MHz
Reverse transfer capacitance	C _{rss}	—	10	—	pF	
Turn-on delay time	t _{d(on)} *	—	5	—	ns	V _{DD} =10V, I _D =150mA
Rise time	t _r *	—	10	—	ns	V _{GS} =4.0V
Turn-off delay time	t _{d(off)} *	—	15	—	ns	R _L =67Ω
Fall time	t _f *	—	10	—	ns	R _G =10Ω

* Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _{SD} *	—	—	1.2	V	I _S = 100mA, V _{GS} =0V

* Pulsed

●Electrical characteristics curves

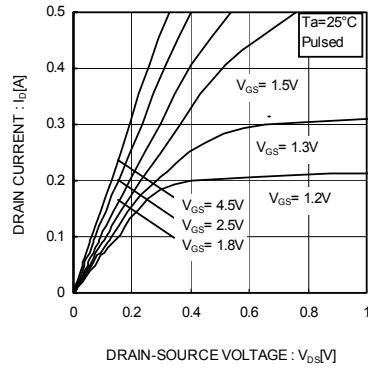


Fig.1 Typical Output Characteristics(I)

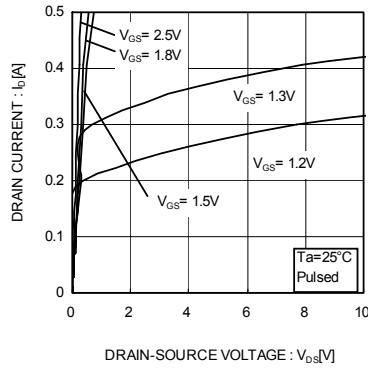


Fig.2 Typical Output Characteristics(II)

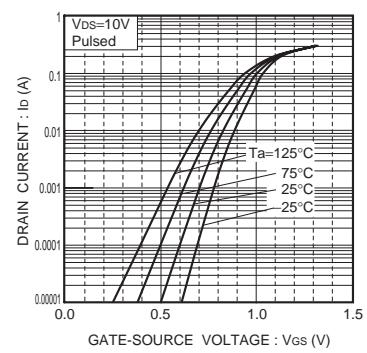


Fig.3 Typical transfer characteristics

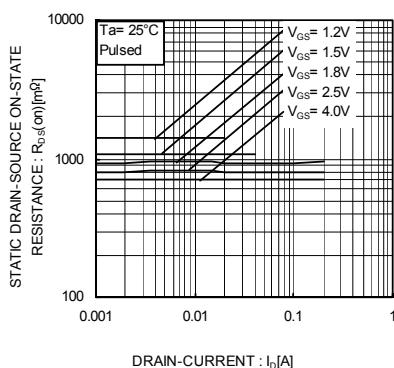


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

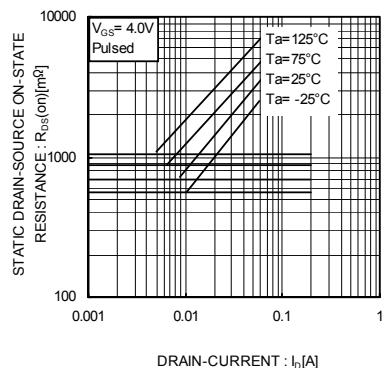


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

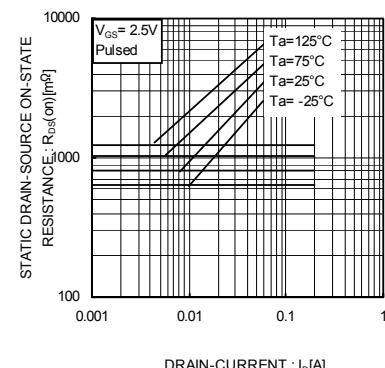


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

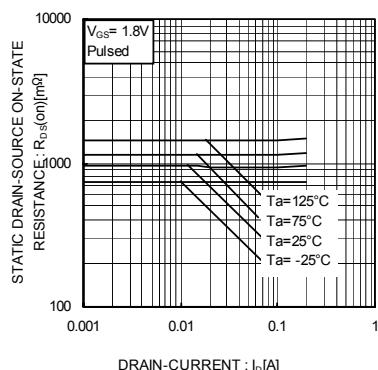


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

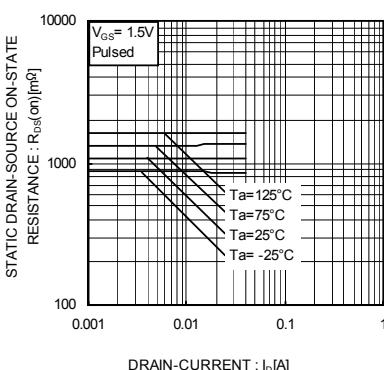


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(V)

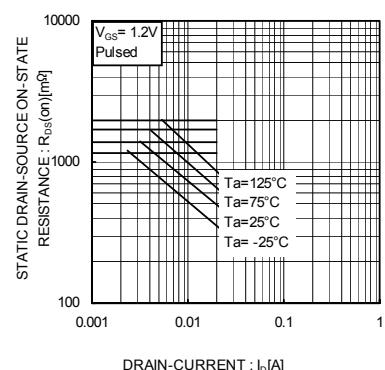


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current(VI)

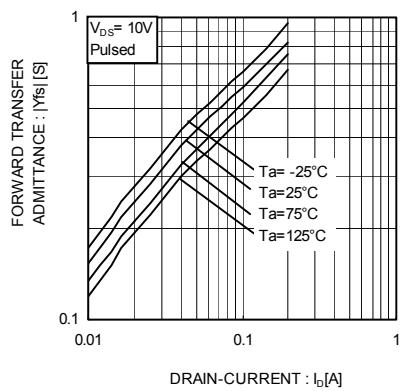


Fig.10 Forward Transfer Admittance vs. Drain Current

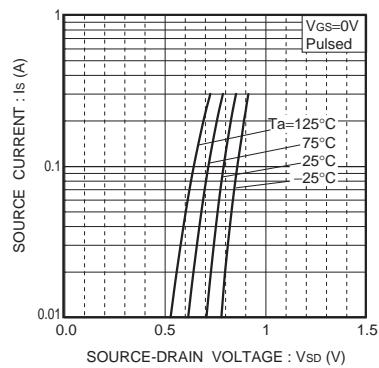


Fig.11 Source current vs. source-drain voltage

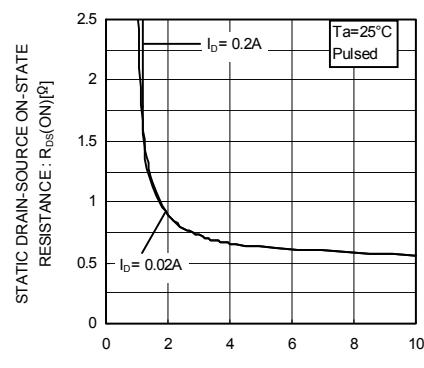


Fig.12 Static Drain-Source On-State Resistance vs. Gate Source Voltage

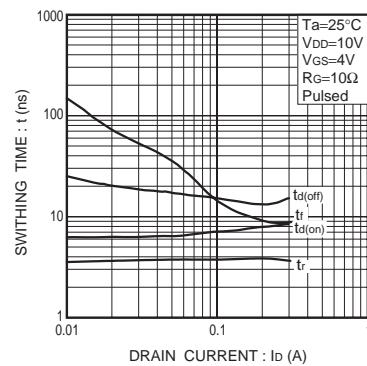


Fig.13 Switching characteristics

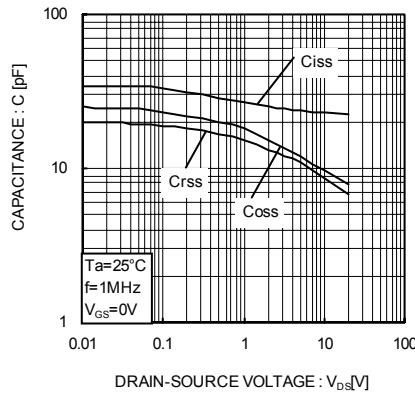


Fig.14 Typical Capacitance vs. Drain-Source Voltage

●Measurement circuit

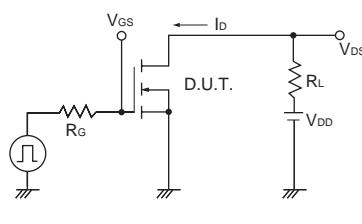


Fig.1-1 Switching time measurement circuit

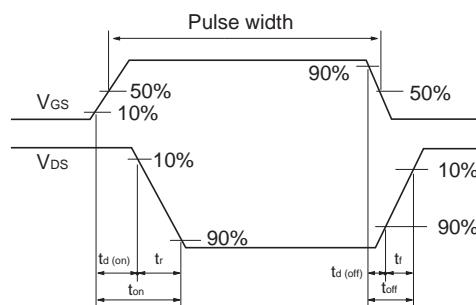


Fig.1-2 Switching waveforms

●Notice

This product might cause chip aging and breakdown under the large electrified environment.
Please consider to design ESD protection circuit

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